

Technical Data Data Sheet N0230, Rev. - 1N4148 (LL4148)

Green Products

1N4148 (LL4148) FAST SWITCHING DIODE

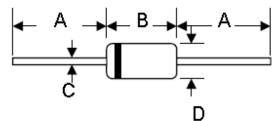
Features:

- Fast Switching Speed
- Glass Package Version for High Reliability
- High Conductance
- Available in Both Through-Hole and Surface Mount Versions
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

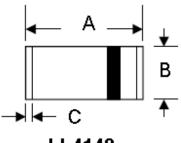
Mechanical Data:

- Case: DO-35, Mini MELF/DL-35
- Terminals: Plated leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode band
- Weight: DO-35 0.13 grams
 - Mini MELF/DL-35 0.05 grams
- Marking: Cathode band

Mechanical Dimensions: In mm/Inches



1N4148





DO-35					
Dim	Min	Max	Min	Max	
A	25.40		1.000		
В		4.00		0.157	
С		0.60		0.024	
D		2.00		0.079	
	in mm		In inch		

MiniMELF					
Dim	MIn	Max	Min	Max	
Α	3.30	3.70	0.130	0.146	
В	1.30	1.60	0.051	0.063	
С	0.28	0.50	0.011	0.020	
	In mm		In inch		

DO-35

Mini MELF/DL-35

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



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Ordering Information:

Device	Package	Shipping
1N4148	DO-35 (Pb-Free)	5000pcs /reel
LL4148	Mini MELF/DL-35 (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings @T_A=25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Forward Continuous Current (Note 1)	I _{FM}	300	mA
Rectified Current(Average), Half Wave Rectification with Resistive Load and $f \ge 50MHz$ (Note 1)	lo	150	mA
Non-Repetitive Peak Forward Surge Current @t=1.0s @t=1.0µs	I _{FSM}	1.0 2.0	А
Power Dissipation(Note 1) Derate Above 25°C	P _D	500 1.68	mW mW/°C
Thermal Resistance, Junction to Ambient Air(Note 1)	R _{θJA}	300	°C/W
Junction and Storage Temperature Range	T _J , T _{STG}	-65 to +175	°C



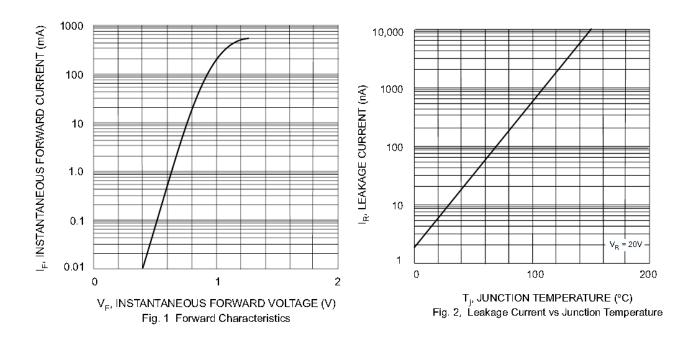
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Characteristic	Symbol	Min	Max	Unit	Test Condition
Forward Voltage	V_{FM}	-	1.0	V	@I _F =10mA
Peak Reverse Current	I _{RM}	-	5.0 50 30 25	μΑ μΑ μΑ nA	@V _R =75V @V _R =70V, T _J =150°C @V _R =20V, T _J =150°C @V _R =20V
Capacitance	Cj	-	4.0	pF	V _R =0V, f=1.0MHz
Reverse Recovery Time	t _{rr}	-	4.0	ns	I_F =10mA to I_R =1.0mA V_R =6.0V, R_L =100 Ω

Electrical Characteristics $@T_A=25^{\circ}C$ unless otherwise specified

Note: 1. Diode on Ceramic substrate 10×8×0.7mm





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